

AVTECH ELECTROSYSTEMS LTD.

NANOSECOND WAVEFORM ELECTRONICS SINCE 1975

P.O. BOX 265 OGDENSBURG, NY U.S.A. 13669-0265 TEL: 888-670-8729 (USA & Canada) or +1-613-686-6675 (Intl) FAX: 800-561-1970 (USA & Canada) or +1-613-686-6679 (Intl)

BOX 5120, LCD MERIVALE OTTAWA, ONTARIO CANADA K2C 3H5

info@avtechpulse.com - http://www.avtechpulse.com/

PERFORMANCE CHECKSHEET

Model: AVO-9A4-B-P0-N-DRXA-VXI-R5

Type: Ultra-High-Speed Laser Diode Driver

S.N.: 13608

Date: September 26, 2017

Basic specifications: →

Output Amplitude: up to -43V, to 50Ω

Pulse Width (FWHM): 1 - 10 nsRise Time (20%-80%): ≤ 500 ps Fall Time (80%-20%): ≤ 750 ps

PRF: 1 Hz - 150 kHz

Jitter, Stability: OK

Prime Power: 100-240V AC, 50-60 Hz.

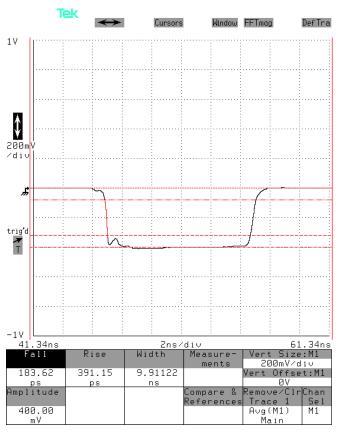
Test Waveforms

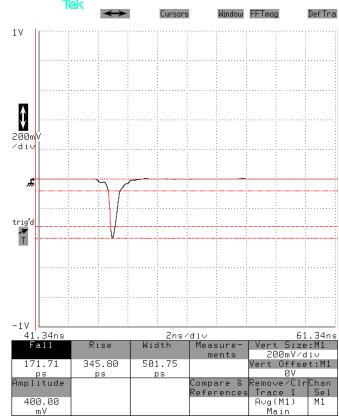
Mainframe output into 50 Ohm load at 10 kHz, 10 ns, -40V,

2 ns/div. 20 V/div (200 mV/div × 40 dB):

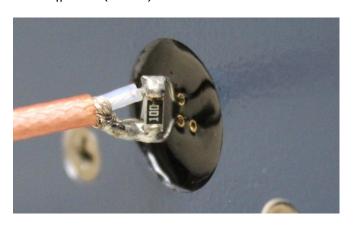
Mainframe output into 50 Ohm load at 10 kHz, < 1 ns, -40V,

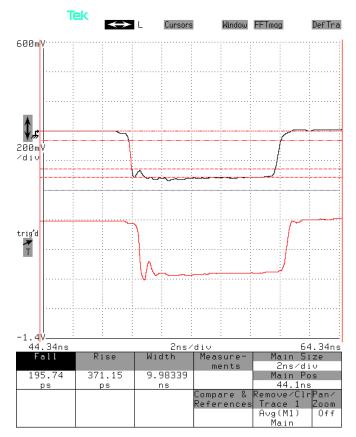
2 ns/div. 20 V/div (200 mV/div × 40 dB):





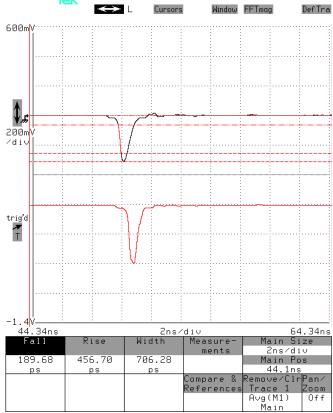
Test method: Short leads are soldered across two 10Ω chip resistors in parallel. A coaxial cable is soldered across the resistor. The signal lead is inserted into the anode pin socket. The ground lead is inserted into one of the other pin sockets (which are grounded). The total effective resistor is $5 \Omega \parallel 50 \Omega (R_{SCOPE}) = 4.5 \Omega$.





Top: Voltage measured across the resistor in response to a -40V, 10 ns pulse. It should be approximately $(-40V / 54.5\Omega) \times 4.5\Omega = +3.3V$, which agrees with the observed waveform. 2V/div (= 200 mV/div × 20 dB), 2 ns/div.

Bottom: "MI" output, approximately +40V / 11. $2V/div (= 200 \text{ mV/div} \times 20 \text{ dB}), 2 \text{ ns/div}.$



Top: Same as waveform on the left, except with a pulse width of < 1 ns.

Bottom: Corresponding "MI" output.